



Quad Monolithic SPST CMOS Analog Switches

DESCRIPTION

Featuring low on-resistance (60 Ω) and fast switching (130 ns), the DG308A is supplied in the "normally open" configuration while DG309 is supplied "normally closed". Input thresholds are high voltage CMOS compatible.

Designed with the Vishay Siliconix PLUS-40 CMOS process to combine low power dissipation with a high breakdown voltage rating of 44 V, each switch conducts equally well in both directions when on, and blocks up to the supply voltage when off. An epitaxial layer prevents latch up.

The DG308B, DG309B upgrades are recommended for new designs.

FEATURES

• ± 15 V analog input range

Low on-resistance: 60 Ω
Fast switching: 130 ns

• Low power dissipation: 30 nW

CMOS logic compatible

Pb-free Available

ROHS

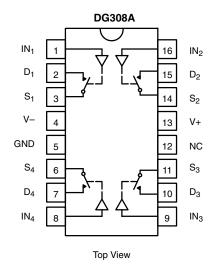
BENEFITS

- Full rail-to-rail analog signal range
- · Low signal error
- Wide dynamic range
- · Single or dual supply capability
- · Static protected logic inputs
- Space savings (TSSOP)

APPLICATIONS

- Portable and battery powered instrumentation
- · Communication systems
- · Computer peripherals
- · High-speed multiplexing

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



For SPST Switches per Package

TRUTH TABLE							
Logic DG308A DG309							
0	OFF	ON					
1	ON	OFF					

 $\label{eq:logic "0" leq 3.5 V} \begin{tabular}{l} Logic "0" leq 3.5 V \\ Logic "1" leq 11 V \\ \end{tabular}$

^{*} Pb containing terminations are not RoHS compliant, exemptions may apply

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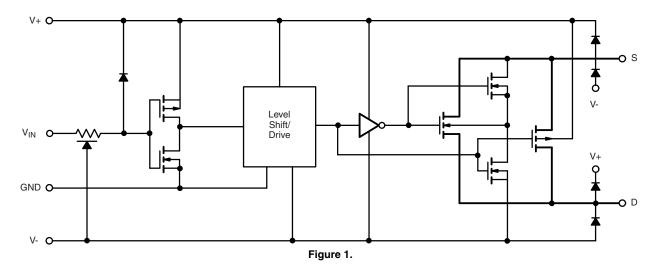
ORDERING INFORMATION					
Temp. Range	Package	Part Number			
0 °C to 70 °C	16-Pin Plastic DIP	DG308ACJ DG308ACJ-E3			
0 6 10 70 6	וטידווו רומטונט טור	DG309CJ DG309CJ-E3			
	40 Die Namen COIO	DG308ADY DG308ADY-E3 DG308ADY-T1 DG308ADY-T1-E3			
- 40 °C to 85 °C	16-Pin Narrow SOIC	DG309DY DG309DY-E3 DG309DY-T1 DG309DY-T1-E3			
- 40 °C 10 85 °C	16-Pin TSSOP	DG308ADQ DG308ADQ-E3 DG308ADQ-T1 DG308ADQ-T1-E3			
	10-PIII 1550P	DG309DQ DG309DQ-E3 DG309DQ-T1 DG309DQ-T1-E3			

ABSOLUTE MAXIMUM RATINGS					
Parameter		Limit	Unit		
Voltages Referenced V+ to V	V-	44			
GND		25	V		
Digital Inputs ^a , V _S , V _D		(V-) - 2 to (V+) + 2 or 20 mA, whichever occurs first			
Current, Any Terminal Excep	ot S or D	30			
Continuous Current	S or D	20	mA		
Continuous Current	(Pulsed at 1 ms, 10 % duty cycle max.)	70			
Ctorogo Tomporoturo	(AK Suffix)	- 65 to 150	°C		
Storage Temperature	(CJ, DY and DQ Suffix)	- 65 to 125	1		
	16-Pin Plastic DIP ^c	470			
Power Dissipation ^b	16-Pin Narrow SOIC and TSSOP ^e	600	mW		
	16-Pin CerDIP ^d	900			

- Notes: a. Signals on S_X , D_X , or IN_X exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 12 mW/°C above 75 °C.
- d. Derate 6.5 mW/°C above 25 °C.
- e. Derate 7.6 mW/°C above 75 °C.



SCHEMATIC DIAGRAM (Typical Channel)



SPECIFICATIONS ^a									
		Test Conditions Unless Specified V+ = 15 V, V- = - 15 V			A Suffix - 55 °C to 125°C		C, D Suffix		
Parameter	Symbol	$V_{IN} = 3.5 \text{ V or } 11 \text{ V}^f$	Temp.b	Typ. ^c	Min. ^d	Max. ^d	Min.d	Max.d	Unit
Analog Switch			•						
Analog Signal Range ^e	V _{ANALOG}		Full		- 15	15	- 15	15	V
Drain-Source On-Resistance	R _{DS(on)}	$V_D = \pm 10 \text{ V}, I_S = 1 \text{ mA}$	Room Full	60		100 150		100 125	Ω
Source Off Leakage Current	I _{S(off)}	$V_S = \pm 14 \text{ V}, V_D = \pm 14 \text{ V}$	Room Full	± 0.1	- 1 100	1 100	- 5 - 100	5 100	
Drain Off Leakage Current	I _{D(off)}	$V_D = \pm 14 \text{ V}, V_S = \pm 14 \text{ V}$	Room Full	± 0.1	- 1 100	1 100	- 5 - 100	5 100	nA
Drain On Leakage Current	I _{D(on)}	$V_D = V_S = \pm 14 \text{ V}$	Room Full	± 0.1	- 1 100	1 100	- 5 - 200	5 200	
Digital Control									
Input Current with Input Voltage High	I _{INH}	V _{IN} = 15 V	Full	0.001		1		1	μΑ
Input Current with Input Voltage Low	I _{INL}	V _{IN} = 0 V	Full	- 0.001	- 1		- 1		μΛ
Input Capacitance	C _{IN}		Room	8					pF
Dynamic Characteristics									
Turn-On Time	t _{ON}	see figure 2	Room	130		200		200	ns
Turn-Off Time	t _{OFF}	300 ligare 2	Room	90		150		150	113
Charge Injection	Q	$C_L = 0.01 \mu F, R_{gen} = 0 \Omega, V_{gen} = 0 V,$	Room	- 10					рС
Source-Off Capacitance	C _{S(off)}		Room	11					
Drain-Off Capacitance	C _{D(off)}	$f = 140 \text{ kHz}, V_S, V_D = 0 \text{ V}$	Room	8					pF
Channel-On Capacitance	C _{D(on)}		Room	27					
Off-Isolation [†]	OIRR	$R_L = 75 \Omega$, $V_S = 2 V_{p-p}$, $f = 500 \text{ kHz}$	Room	78					dB

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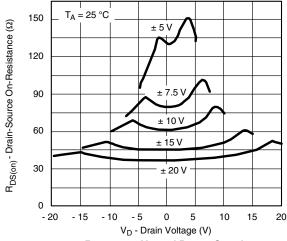
SPECIFICATIONS ^a									
		Test Conditions Unless Specified V+ = 15 V, V- = - 15 V			_	uffix to 125°C	C, D	Suffix	
Parameter	Symbol	$V_{1N} = 13 \text{ V}, V_{1N} = -13 \text{ V}$ $V_{1N} = 3.5 \text{ V or } 11 \text{ V}^{f}$	Temp.b	Typ. ^c	Min. ^d	Max. ^d	Min.d	Max. ^d	Unit
Power Supplies									
Positive Supply Current	I+	all channels on or off	Room Full	0.001		10 100		10 100	μА
Negative Supply Current	I-	V _{IN} = 0 V or 15 V	Room Full	- 0.001	- 10 - 100		- 100		μΑ

Notes:

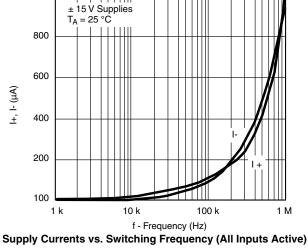
- a. Refer to PROCESS OPTION FLOWCHART.
- b.Room = 25 °C, Full = as determined by the operating temperature suffix.
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- e.Guaranteed by design, not subject to production test.
- f. V_{IN} = input voltage to perform proper function.

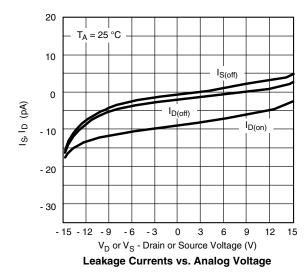
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

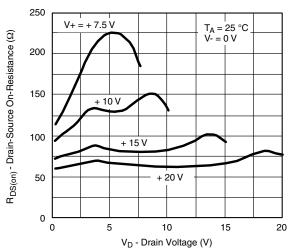
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



R_{DS(on)} vs. V_D and Power Supply



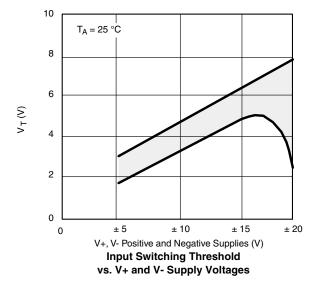


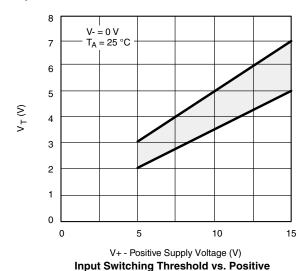




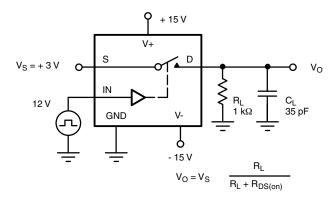


TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)





Supply Voltage



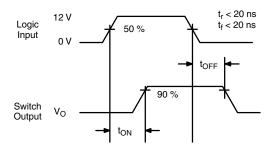


Figure 2. Switching Time

APPLICATIONS

Single Supply Operation

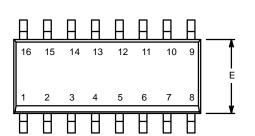
The DG308A and DG309 will switch positive analog signals while using a single positive supply. This will allow use in many applications where only one supply is available. The trade-offs or performance given up while using single supplies are:

1) increased $R_{DS(on)}$ and 2) slower switching speed. As stated in the absolute maximum ratings section of the data sheet, the analog voltage should not go above or below the supply voltages which in single supply operation are V+ and 0 V.

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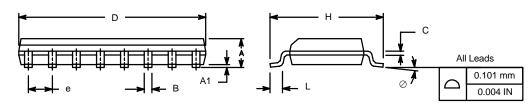
SOIC (NARROW): 16-LEAD
JEDEC Part Number: MS-012



	MILLIMETERS		INC	HES		
Dim	Min	Max	Min	Max		
Α	1.35	1.75	0.053	0.069		
A ₁	0.10	0.20	0.004	0.008		
В	0.38	0.51	0.015	0.020		
С	0.18	0.23	0.007	0.009		
D	9.80	10.00	0.385	0.393		
E	3.80	4.00	0.149	0.157		
е	1.27	BSC	0.050	BSC		
Н	5.80	6.20	0.228	0.244		
L	0.50	0.93	0.020	0.037		
0	0°	8°	0°	8°		
FCN: S-03946—Rev. F. 09- Jul-01						

ECN: S-03946—Rev. F, 09-Jul-01

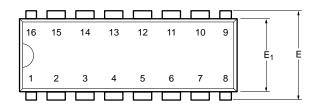
DWG: 5300

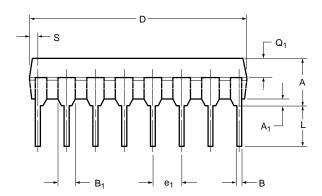


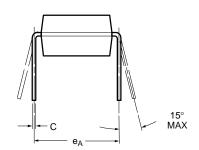
Document Number: 71194 www.vishay.com 02-Jul-01 sww.vishay.com



PDIP: 16-LEAD





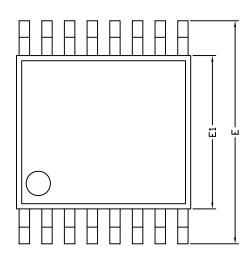


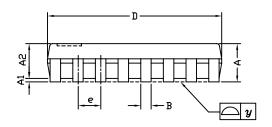
	MILLIMETERS		INC	CHES		
Dim	Min	Max	Min	Max		
Α	3.81	5.08	0.150	0.200		
A ₁	0.38	1.27	0.015	0.050		
В	0.38	0.51	0.015	0.020		
B ₁	0.89	1.65	0.035	0.065		
С	0.20	0.30	0.008	0.012		
D	18.93	21.33	0.745	0.840		
Е	7.62	8.26	0.300	0.325		
E ₁	5.59	7.11	0.220	0.280		
e ₁	2.29	2.79	0.090	0.110		
e _A	7.37	7.87	0.290	0.310		
L	2.79	3.81	0.110	0.150		
Q_1	1.27	2.03	0.050	0.080		
S	0.38	1.52	.015	0.060		
ECN: S-03946—Rev. D, 09-Jul-01 DWG: 5482						

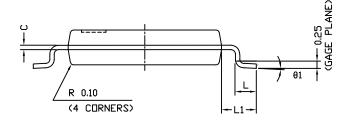
Document Number: 71261 www.vishay.com 06-Jul-01 www.vishay.com



TSSOP: 16-LEAD







	DII	MENSIONS IN MILLIMETER	S
Symbols	Min	Nom	Max
Α	-	1.10	1.20
A1	0.05	0.10	0.15
A2	=	1.00	1.05
В	0.22	0.28	0.38
С	=	0.127	=
D	4.90	5.00	5.10
E	6.10	6.40	6.70
E1	4.30	4.40	4.50
е	-	0.65	-
L	0.50	0.60	0.70
L1	0.90	1.00	1.10
у	=	-	0.10
θ1	0°	3°	6°
ECN: S-61920-Rev. D, 23-0	Oct-06		

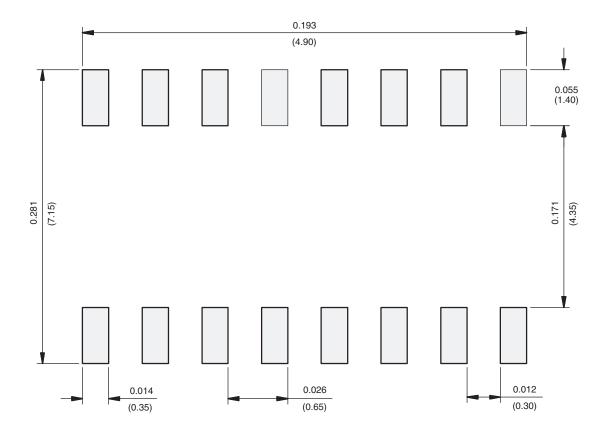
ECN: S-61920-Rev. D, 23-Oct-06

DWG: 5624

Document Number: 74417
23-Oct-06
www.vishay.com



RECOMMENDED MINIMUM PAD FOR TSSOP-16

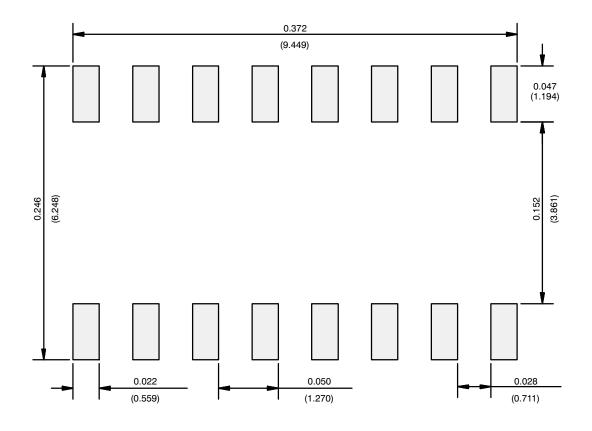


Recommended Minimum Pads Dimensions in inches (mm)

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RECOMMENDED MINIMUM PADS FOR SO-16



Recommended Minimum Pads Dimensions in Inches/(mm)

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